

CLAIMS

1. A diffusion barrier alloy film having a diffusion barrier layer made of an Re-W alloy σ phase
5 containing 12.5 to 56.5% of W in terms of atomic composition and the remainder of Re excluding unavoidable impurities.

2. A diffusion barrier alloy film having a diffusion barrier layer made essentially of an Re-W alloy σ
10 phase containing 12.5 to 56.5% of W and 20 to 60% of Re in terms of atomic composition, the total quantity of W and Re being 50% or greater, and, excluding unavoidable impurities, the remainder being of at least one selected from Cr, Ni, Co, and Fe.

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3. A diffusion barrier alloy film according to claim 1 or 2, wherein said diffusion barrier layer is formed by performing Re or Re alloy plating and W or W alloy plating on a surface of a metal base, and thereafter heat-
20 treating the plated metal base at 1200°C or higher.

4. A diffusion barrier alloy film according to claim 1 or 2, further having an Re-dispersed layer with Re dispersed therein, disposed in an interface between said
25 diffusion barrier layer and a metal base to be coated with said diffusion barrier layer.

5. A diffusion barrier alloy film according to claim 4, wherein said Re-dispersed layer and said diffusion barrier layer are formed by performing Re alloy plating in two stages with different concentrations of Re on a surface of the metal base, performing W alloy plating on the plated surface of the metal base, and thereafter heat-treating the plated metal base at 1200°C or higher.

6. A diffusion barrier alloy film according to claim 1 or 2, wherein said diffusion barrier layer has a surface coated with a diffusion alloy layer containing 10% or greater and less than 50% of Al, Cr, or Si in terms of atomic composition.

7. A diffusion barrier alloy film according to claim 6, further having a W-dispersed layer with W dispersed therein, between said diffusion barrier layer and said diffusion alloy layer.

8. A method of manufacturing a diffusion barrier alloy film having a diffusion barrier layer made of an Re-W alloy, comprising performing Re or Re alloy plating and W or W alloy plating on a surface of a metal base, and thereafter heat-treating the plated metal base at 1200°C or higher.

9. A method of manufacturing a diffusion barrier alloy film having a diffusion barrier layer made of an Re-dispersed layer with Re dispersed therein and an Re-W alloy,

comprising performing Re alloy plating in two stages on the surface of the metal base, performing W alloy plating on a plated surface of the metal base, and thereafter heat-treating the plated metal base at 1200°C or higher.

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10. A method of forming a diffusion barrier alloy film, comprising:

forming a diffusion barrier layer made of an Re-W alloy on a surface of a metal base by fused-salt plating;

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forming a diffusion alloy layer containing 10% or greater and less than 50% of Al, Cr, or Si in terms of atomic composition, on a surface of said diffusion barrier layer by fused-salt plating.

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11. A method of forming a diffusion barrier alloy film, comprising:

forming surface irregularities on a surface of a metal base;

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forming a diffusion barrier layer made of an Re-W alloy on the surface of the metal base on which the surface irregularities have been formed;

forming surface irregularities on a surface of said diffusion barrier layer; and

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forming a corrosion-resistant alloy layer on the surface of said diffusion barrier layer on which the surface irregularities have been formed.

12. A method of forming a diffusion barrier alloy film, comprising:

forming surface irregularities on a surface of a metal base;

5 forming a diffusion barrier layer made of an Re-W alloy on the surface of the metal base on which the surface irregularities have been formed;

forming surface irregularities on a surface of said diffusion barrier layer; and

10 forming a wear-resistant layer on the surface of said diffusion barrier layer on which the surface irregularities have been formed.

13. A method according to any one of claims 8 through 12, wherein said Re-W alloy is made of an Re-W alloy σ phase containing 12.5 to 56.5% of W in terms of atomic composition and the remainder of Re excluding unavoidable impurities.

20 14. A method according to any one of claims 8 through 12, wherein said Re-W alloy is made essentially of an Re-W alloy σ phase containing 12.5 to 56.5% of W and 20 to 60% of Re in terms of atomic composition, the total quantity of W and Re being 50% or greater, and, excluding
25 unavoidable impurities, the remainder being of at least one selected from Cr, Ni, Co, and Fe.

15. A method according to claim 8 or 9, further comprising the step of diffusing Al, Cr, or Si after the metal base is heat-treated.

5 16. A method according to claim 8 or 9, further comprising the step of plating the surface of said metal base with Cr in advance.

10 17. A high-temperature apparatus member comprising a metal base having a surface coated with a diffusion barrier layer made of an Re-W alloy σ phase containing 12.5 to 56.5% of W in terms of atomic composition and the remainder of Re excluding unavoidable impurities.

15 18. A high-temperature apparatus member comprising a metal base having a surface coated with a diffusion barrier layer made essentially of an Re-W alloy σ phase containing 12.5 to 56.5% of W and 20 to 60% of Re in terms of atomic composition, the total quantity of W and Re
20 being 50% or greater, and, excluding unavoidable impurities, the remainder being of at least one selected from Cr, Ni, Co, and Fe.

25 19. A high-temperature apparatus member according to claim 17 or 18, wherein said diffusion barrier layer has a surface coated with a diffusion alloy layer containing 10% or greater and less than 50% of Al, Cr, or Si in terms of atomic composition.

20. A high-temperature apparatus member according to claim 17 or 18, further comprising an Re-dispersed layer with Re dispersed therein, between said metal base and said
5 diffusion barrier layer.

21. A high-temperature apparatus member according to claim 19, further comprising a W-dispersed layer with W dispersed therein, between said diffusion barrier layer and
10 said diffusion alloy layer.

22. A high-temperature apparatus member according to claim 19, wherein said diffusion alloy layer has a surface covered with a ceramics layer.
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23. A high-temperature apparatus member according to claim 17 or 18, wherein said diffusion barrier layer has a surface coated with a heat-resistant alloy film.

20 24. A high-temperature apparatus member according to claim 17 or 18, wherein said diffusion barrier layer has a surface coated with a wear-resistant film.